Q.P. C	ode: 1	6 EE 2	207										R1	6
Reg.	No:]		
	SIDE	HAR	TH IN	STIT	UTE C	OF EN (AU	GINE		IG & 1 JS)	ECH	INOL	ogy:: Pu	ITTUR	
	B.T	ech I	l Year BAS	' II Se IC El	emeste LECTI	er Su RICA	pplei	menta ELEC	TRON	amii NICS	natior ENG	ns March INEERIN	2021 G	
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	0.011	ouro		(An	swer a	II Six	Unite	6 X 1	0 = 6	0 Ma	rks)			(J. U
							PA UI	RT-A			ng turing			
1	Three series total o dissip	resist across current ated in	ances s 20V t of the n each	of val DC su e circ resiste	ues 2Ω ipply. (uit. iii) or.	2,3Ω a Calcul The v	and 59 ate i) roltage	Ω are Equiv e drop	connec alent re across	eted i esista s eacl	n serie ince of n resis	es are conn f the circuit stor. iv) Th	ected in . ii) The e power	10N
	Б						an.	OR						
2	a Ex	plain I	Resisti	ve net	works.									5N
	D LA	Jiani n	iuuctiv	e netw	UIKS.		TIN							3 IV
2	o Sto	to sup		tiont	haanan		UN	11-11						-
		104 (F		22			M- 2- 1-1	I		0	14		
			L						1					8 M
		~					(OR						
4	a De	fine ar	nd expl	lain al	oout In	ipedar	ice pa	aramet	ers.					5M
	U DC	inc ai	iu exp	iani ai	Jour 1.	- parai	TINI	5. TT III						2141
5	o Ev	nloin a	hout	minair	lasfo	novoti		DC M	otora	n dat	a:1			5 N A
3	b Ca hav	lculate	the v 74 con	value ducto	of Tor ors, 2 p	que e aths i	stabli n par	ished 1 allel, 2	by the 24mwb	arm arm	an. ature per p	of a 4-pol	e motor the total	2141
	arn	nature	curren	t is 50	DA.									5M
(P				0	2	•	OR						
6	a De	rive El	MF eq	uation	n of a ti	ansto	rmer.	aform	n haa	10 ~~	and-	my turner C	algulata	5M
	the	numb	er of p	orimar	y turns	and p	riman PA	ry and RT-B	second	lary o	current	ts.	acuiate	5M
							UN	IT-IV						
7	a Wł	nat is I	Doping	? Des	cribe F	' -and]	N-typ	e semi	condu	ctors	1.11			5M

a What is Doping? Describe P-and N-type semiconducb Explain the behavior of PN junction diode.

5M

Q.P. Code: 16EE207

		OR	
8	a	With neat diagram, explain the working principle of Half Wave Rectifier. Draw its input and Output waveforms.	5M
	b	Derive the expression for Ripple factor and Efficiency of Half Wave Rectifier.	5M
9	a b	Describe the Voltage Divider Bias Network of BJT with diagram and equations. What is the purpose of bias in a transistor circuit? Explain the Q point and DC	5M
		load line in BJT. OR	5M
10	a	Discuss the transfer and output characteristics of n-channel JFET with diagrams.	5M
	b	Compare BJT and JFET with its properties.	5M
		UNIT-VI	
11	a	With neat diagram, explain the operation of LC tuned transistor oscillator.	5 M
	b	Discuss the operation of Hartley oscillator with diagram.	5M
		OR	
12	a	Draw an inverting amplifier of operational amplifier and derive its closed loop gain.	5M
	b	Determine the closed loop gain of a non-inverting operational amplifier and draw its diagram.	5M

R16

*** END ***